TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

2SC5066

VHF~UHF Band Low Noise Amplifier Applications

• Low noise figure, high gain.

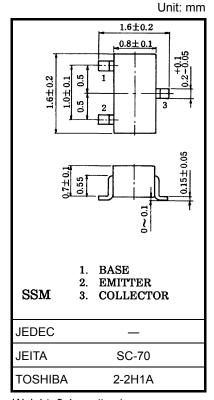
• NF = 1.1dB, $|S_{21e}|^2 = 12dB$ (f = 1 GHz)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Collector-base voltage	V_{CBO}	20	V	
Collector-emitter voltage	V _{CEO}	12	V	
Emitter-base voltage	V _{EBO}	3	V	
Base current	Ι _Β	15	mA	
Collector current	IC	30	mA	
Collector power dissipation	PC	100	mW	
Junction temperature	Tj	125	°C	
Storage temperature range	T _{stg}	-55 to 125	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



Weight: 2.4 mg (typ.)

Microwave Characteristics (Ta = 25°C)

Characteristics	Characteristics Symbol		Min	Тур.	Max	Unit	
Transition frequency	f _T	V _{CE} = 5 V, I _C = 10 mA	5	7	_	GHz	
Insertion gain	S _{21e} ² (1)	V _{CE} = 5 V, I _C = 10 mA, f = 500 MHz	_	17	_	dB	
	$ S_{21e} ^2$ (2)	V _{CE} = 5 V, I _C = 10 mA, f = 1 GHz	8.5	12	_	uБ	
Noise figure	NF (1)	$V_{CE} = 5 \text{ V}, I_{C} = 3 \text{ mA}, f = 500 \text{ MHz}$	_	1	_	dB	
Noise ligure	NF (2)	$V_{CE} = 5 \text{ V, } I_{C} = 3 \text{ mA, } f = 1 \text{ GHz}$	_	1.1	2.0	ub	

Electrical Characteristics (Ta = 25°C)

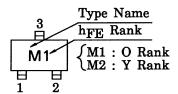
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	V _{CB} = 10 V, I _E = 0	_	_	1	μА
Emitter cut-off current	I _{EBO}	V _{EB} = 1 V, I _C = 0	_	_	1	μА
DC current gain	h _{FE} (Note 1)	V _{CE} = 5 V, I _C = 10 mA	80	_	240	
Output capacitance	C _{ob}	V _{CB} = 5 V, I _E = 0, f = 1 MHz (Note 2)	_	0.7	_	pF
Reverse transfer capacitance	C _{re}	VCB = 2 V, IE = 0, I = 1 MILIZ (Note 2)	_	0.45	0.9	pF

Note 1: hFE classification O: 80 to 160, Y: 120 to 240

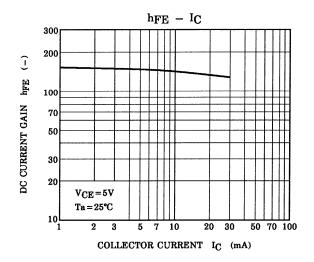
Note 2: C_{re} is measured by 3 terminal method with capacitance bridge.

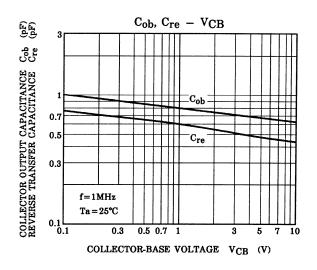
Start of commercial production 1993-07

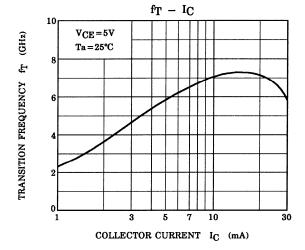
Marking

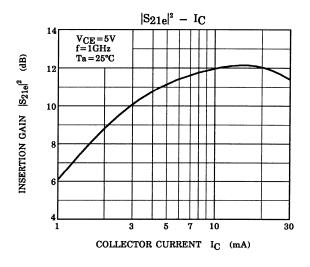


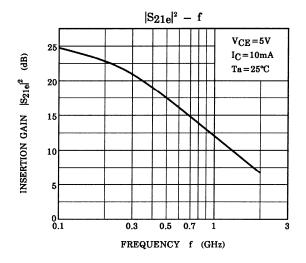
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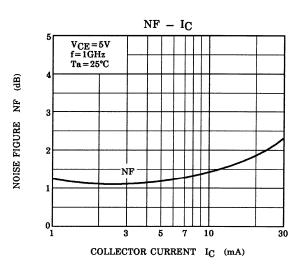




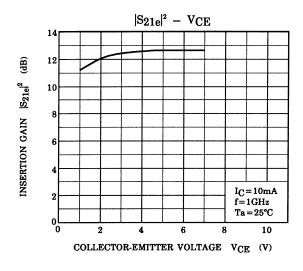


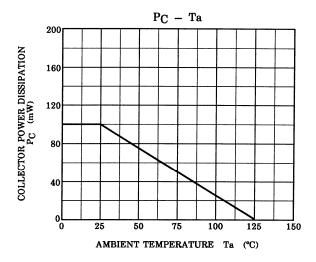






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S-Parameter $Z_O = 50 \Omega$, $Ta = 25^{\circ}C$

$V_{CE} = 5 V$, $I_C = 5 mA$

Frequency	S11		S21		S12		S22	
(MHz)	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.
200	0.753	-43.7	10.247	140.6	0.040	65.6	0.827	-22.6
400	0.531	-75.1	7.684	117.1	0.060	57.1	0.648	-30.3
600	0.384	-96.4	5.815	103.0	0.074	56.1	0.551	-32.0
800	0.305	-112.6	4.523	93.6	0.086	57.0	0.500	-32.3
1000	0.255	-126.5	3.788	86.3	0.099	58.9	0.472	-32.4
1200	0.224	-138.4	3.244	80.7	0.112	60.2	0.455	-32.2
1400	0.203	-150.1	2.833	75.4	0.127	60.3	0.442	-32.6
1600	0.187	-159.4	2.529	70.6	0.139	60.0	0.434	-33.0
1800	0.174	-166.5	2.283	66.7	0.150	60.3	0.429	-32.6
2000	0.176	-171.2	2.107	63.0	0.164	59.2	0.428	-32.2

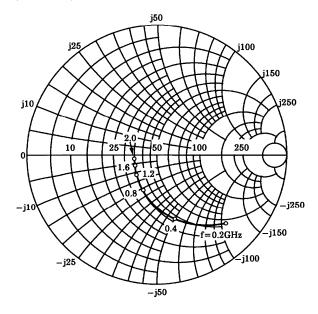
$V_{CE} = 5 V$, $I_C = 10 mA$

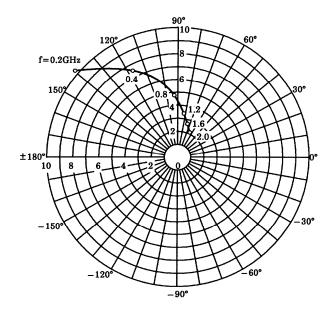
Frequency	S11		S21		S12		S22	
(MHz)	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.
200	0.591	-58.0	14.955	129.6	0.034	64.3	0.714	-27.5
400	0.367	-90.3	9.581	107.5	0.052	61.9	0.534	-30.8
600	0.260	-110.7	6.781	96.1	0.067	63.9	0.462	-30.1
800	0.209	-126.9	5.207	88.6	0.083	65.2	0.428	-29.2
1000	0.178	-141.8	4.269	82.5	0.100	66.4	0.412	-28.6
1200	0.160	-153.7	3.618	77.7	0.117	66.7	0.403	-28.3
1400	0.150	-166.3	3.152	72.7	0.135	65.4	0.398	-28.8
1600	0.141	-175.2	2.801	68.7	0.149	64.0	0.393	-29.4
1800	0.130	178.2	2.521	65.0	0.163	63.4	0.392	-29.0
2000	0.133	174.0	2.314	61.7	0.179	61.3	0.395	-28.6

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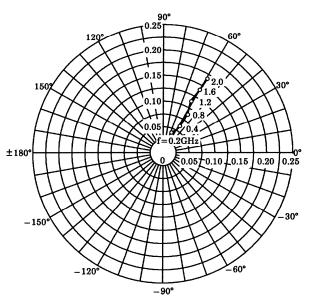
 $\begin{array}{l} S_{11e} \\ V_{CE} = 5V \\ I_{C} = 5mA \\ Ta = 25^{\circ}C \\ (UNIT:\Omega) \end{array}$

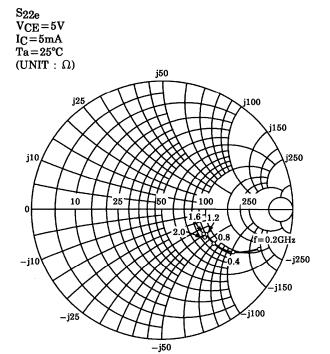






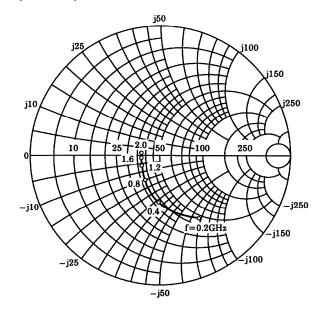
 $\begin{array}{l} S_{12e} \\ V_{CE} = 5V \\ I_{C} = 5mA \\ Ta = 25^{\circ}C \end{array}$

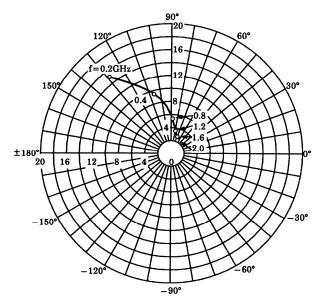




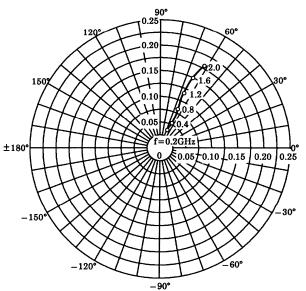
 $\begin{array}{l} S_{11e} \\ V_{CE}\!=\!5V \\ I_{C}\!=\!10\text{mA} \\ Ta\!=\!25^{\circ}\!C \\ (UNIT:\Omega) \end{array}$







 $\begin{array}{l} S_{12e} \\ V_{CE} = 5V \\ I_{C} = 10 mA \\ Ta = 25 ^{\circ}C \end{array}$



 $\begin{array}{c} S22e \\ VCE = 5V \\ IC = 10mA \\ Ta = 25^{\circ}C \\ (UNIT: \Omega) \end{array}$

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